

## Current Transfer Ratio

| Classification<br>(Note 1) | Current Transfer Ratio (%)<br>(I <sub>C</sub> /I <sub>F</sub> )   |     | Marking Of Classification                              |
|----------------------------|---|-----|--|
|                            | I <sub>F</sub> = 5mA, V <sub>CE</sub> = 5V, T <sub>a</sub> = 25°C |     |  |
|                            | Min   | Max |  |
| Blank                      | 50  | 600 | Blank ,Y <sup>■</sup> ,YE,G,G <sup>■</sup> ,GR,B,BL,GB |
| Rank Y                     | 50  | 150 | YE, Y <sup>■</sup>                                     |
| Rank GR                    | 100   | 300 | GR, G, G <sup>■</sup>                                  |
| Rank BL                    | 200   | 600 | BL, B  |
| Rank GB                    | 100   | 600 | GB , GR , G, G <sup>■</sup> , BL , B                   |
| Rank YH                    | 75  | 150 | Y <sup>■</sup>   |
| Rank GRL                   | 100   | 200 | G  |
| Rank GRH                   | 150   | 300 | G <sup>■</sup>   |
| Rank BLL                   | 200   | 400 | B  |

Note 1: EX, Rank GB: TLP181 (GB)

Note: Application, type name for certification test, please use standard product type name, i. e.  
TLP181 (GB): TLP181

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristic                                       |  | Symbol              | Rating     | Unit             |
|--|--|---------------------|------------|------------------|
| LED  | Forward current                                  | I <sub>F</sub>      | 50         | mA               |
|  | Forward current derating (Ta ≥ 89°C)             | ΔI <sub>F</sub> /°C | -1.4       | mA/°C            |
|  | Pulse forward current (100μs pulse, 100pps)      | I <sub>FP</sub>     | 1          | A                |
|  | Reverse voltage                                  | V <sub>R</sub>      | 5          | V                |
|  | Diode power dissipation                          | P <sub>D</sub>      | 100        | mW               |
|  | Diode power dissipation derating (Ta ≥ 89°C)     | ΔP <sub>D</sub> /°C | -2.8       | mW/°C            |
|  | Junction temperature                             | T <sub>j</sub>      | 125        | °C               |
| Detector   | Collector-emitter voltage                        | V <sub>CEO</sub>    | 80         | V                |
|  | Emitter-collector voltage                        | V <sub>ECO</sub>    | 7          | V                |
|  | Collector current                                | I <sub>C</sub>      | 50         | mA               |
|  | Collector power dissipation                      | P <sub>C</sub>      | 150        | mW               |
|  | Collector power dissipation derating (Ta ≥ 25°C) | ΔP <sub>C</sub> /°C | -1.5       | mW/°C            |
|  | Junction temperature                             | T <sub>j</sub>      | 125        | °C               |
| Storage temperature range                            |  | T <sub>stg</sub>    | -55 to 125 | °C               |
| Operating temperature range                          |  | T <sub>opr</sub>    | -55 to 110 | °C               |
| Lead soldering temperature (10 s)                    |  | T <sub>sol</sub>    | 260        | °C               |
| Total package power dissipation                      |  | P <sub>T</sub>      | 200        | mW               |
| Total package power dissipation derating (Ta ≥ 25°C) |  | ΔP <sub>T</sub> /°C | -2.0       | mW/°C            |
| Isolation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1)   |  | BV <sub>S</sub>     | 3750       | V <sub>rms</sub> |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: Pin1, 3 shorted together and pins 4, 6 shorted together

## Recommended Operating Conditions

| Characteristic    | Symbol          | Min | Typ. | Max | Unit |
|-------------------|-----------------|-----|------|-----|------|
| Supply voltage    | V <sub>CC</sub> | —   | 5    | 48  | V    |
| Forward current   | I <sub>F</sub>  | —   | 16   | 20  | mA   |
| Collector current | I <sub>C</sub>  | —   | 1    | 10  | mA   |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## Electrical Characteristics (Ta = 25°C)

| Characteristic |                                     | Symbol        | Test Condition  | Min | Typ.        | Max         | Unit          |
|----------------|-------------------------------------|---------------|---|-----|-------------|-------------|---------------|
| LED            | Forward voltage                     | $V_F$         | $I_F = 10 \text{ mA}$   | 1.0 | 1.15        | 1.3         | V             |
|                | Reverse current                     | $I_R$         | $V_R = 5 \text{ V}$   | —   | —           | 10          | $\mu\text{A}$ |
|                | Capacitance                         | $C_T$         | $V = 0 \text{ V}, f = 1 \text{ MHz}$  | —   | 30          | —           | pF            |
| Detector       | Collector-emitter breakdown voltage | $V_{(BR)CEO}$ | $I_C = 0.5 \text{ mA}$  | 80  | —           | —           | V             |
|                | Emitter-collector breakdown voltage | $V_{(BR)ECO}$ | $I_E = 0.1 \text{ mA}$  | 7   | —           | —           | V             |
|                | Collector dark current              | $I_{CEO}$     | $V_{CE} = 48 \text{ V},$<br>( Ambient light below 1000 lx) (Note 1)                         | —   | 0.01<br>(2) | 0.1<br>(10) | $\mu\text{A}$ |
|                |                                     |               | $V_{CE} = 48 \text{ V}, T_a = 85^\circ\text{C},$<br>( Ambient light below 1000 lx) (Note 1) | —   | 2<br>(4)    | 50<br>(50)  | $\mu\text{A}$ |
|                | Capacitance (collector to emitter)  | $C_{CE}$      | $V = 0 \text{ V}, f = 1 \text{ MHz}$  | —   | 10          | —           | pF            |

Note 1: Please use standard electric lamp to light up the device's marking surface.

## Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic                       | Symbol                | Test Condition  | Min | Typ. | Max | Unit          |
|--------------------------------------|-----------------------|---|-----|------|-----|---------------|
| Current transfer ratio               | $I_C/I_F$             | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$<br>Rank GB   | 50  | —    | 600 | %             |
|                                      |                       |   | 100 | —    | 600 |               |
| Saturated CTR                        | $I_C/I_F(\text{sat})$ | $I_F = 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$<br>Rank GB | —   | 60   | —   | %             |
|                                      |                       |   | 30  | —    | —   |               |
| Collector-emitter saturation voltage | $V_{CE(\text{sat})}$  | $I_C = 2.4 \text{ mA}, I_F = 8 \text{ mA}$              | —   | —    | 0.4 | V             |
|                                      |                       | $I_C = 0.2 \text{ mA}, I_F = 1 \text{ mA}$<br>Rank GB   | —   | 0.2  | —   |               |
|                                      |                       |   | —   | —    | 0.4 |               |
| Off-state collector current          | $I_{C(\text{off})}$   | $V_F = 0.7 \text{ V}, V_{CE} = 48 \text{ V}$            | —   | 1    | 10  | $\mu\text{A}$ |

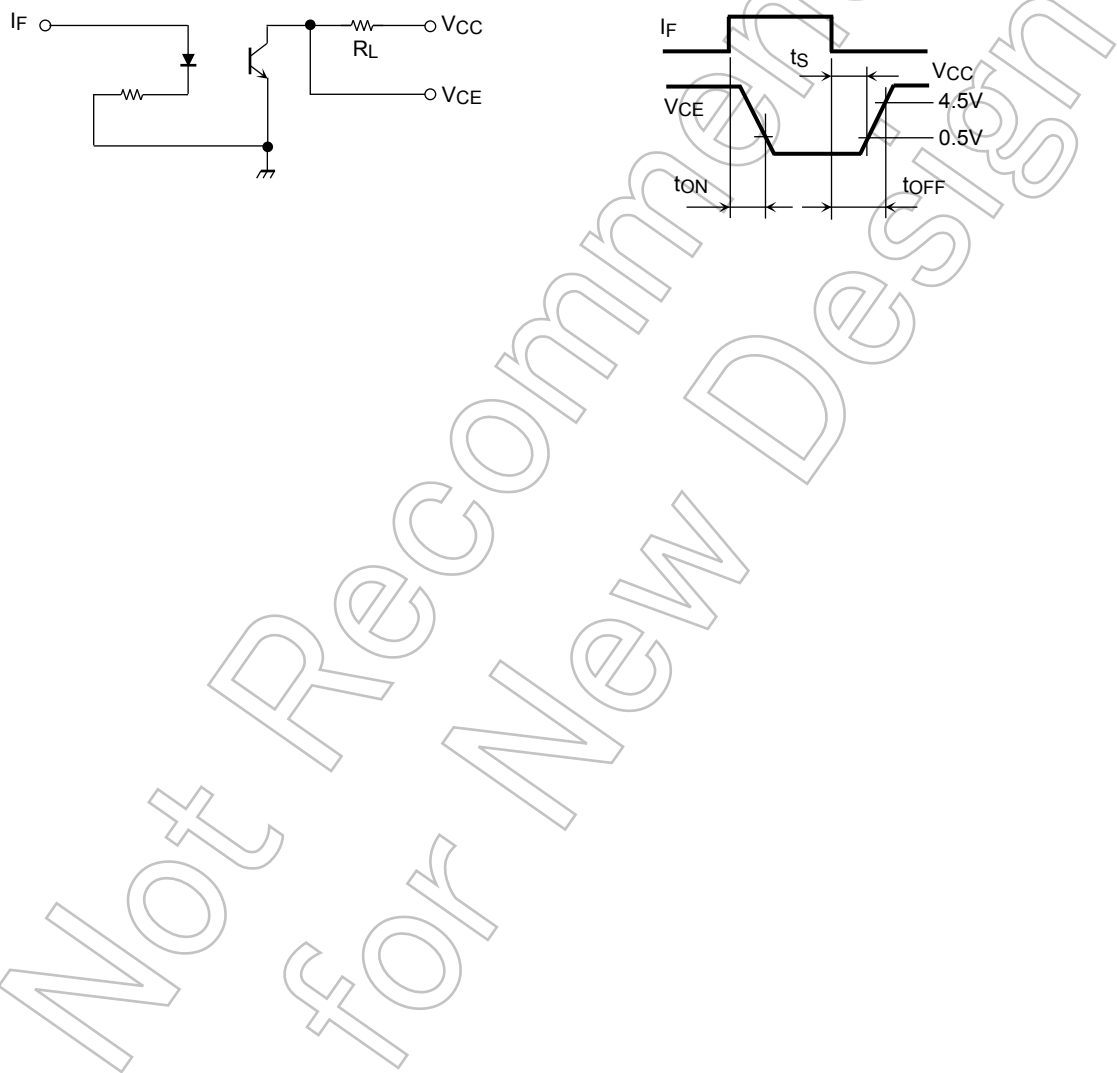
## Isolation Characteristics (Ta = 25°C)

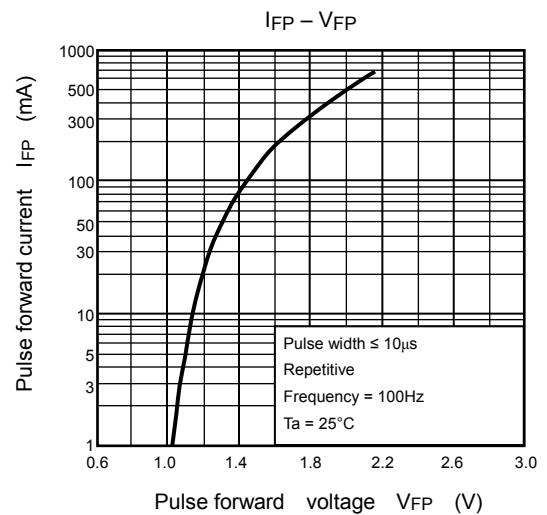
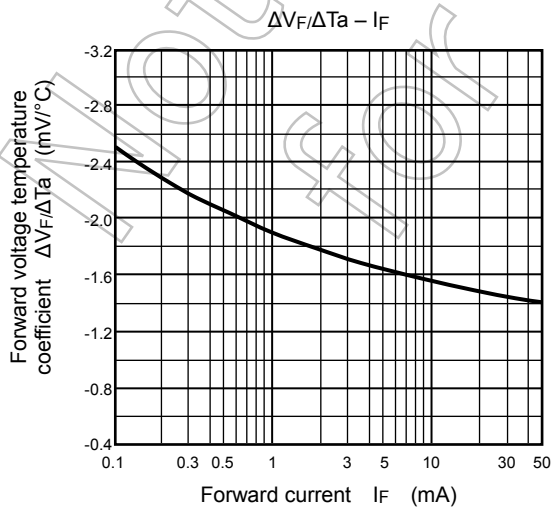
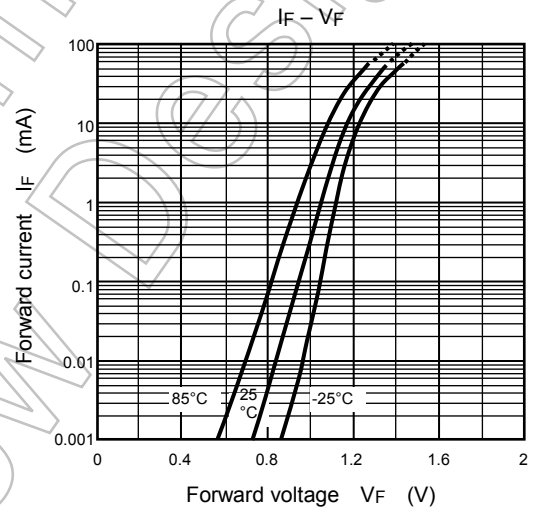
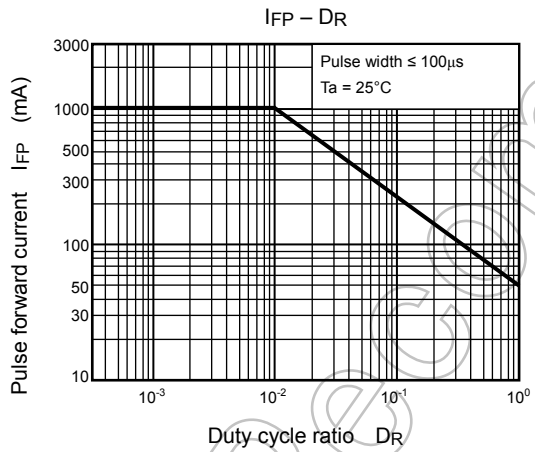
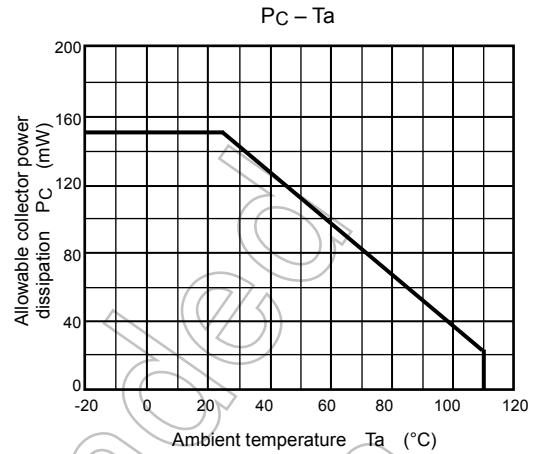
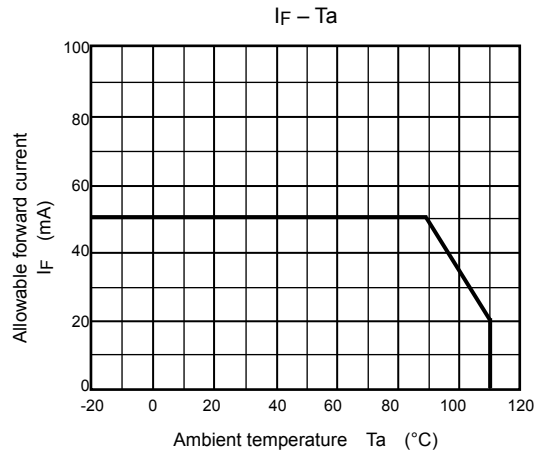
| Characteristic                | Symbol | Test Condition                                | Min                | Typ.      | Max | Unit             |
|-------------------------------|--------|---|--------------------|-----------|-----|------------------|
| Capacitance (input to output) | $C_S$  | $V_S = 0 \text{ V}, f = 1 \text{ MHz}$        | —                  | 0.8       | —   | pF               |
| Isolation resistance          | $R_S$  | $V_S = 500 \text{ V}, \text{R.H.} \leq 60 \%$ | $1 \times 10^{12}$ | $10^{14}$ | —   | $\Omega$         |
| Isolation voltage             | $BV_S$ | AC, 60 s                                      | 3750               | —         | —   | V <sub>rms</sub> |

Switching Characteristics (Ta = 25°C)

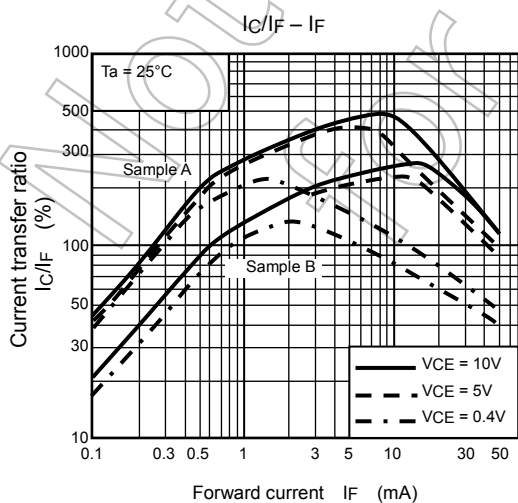
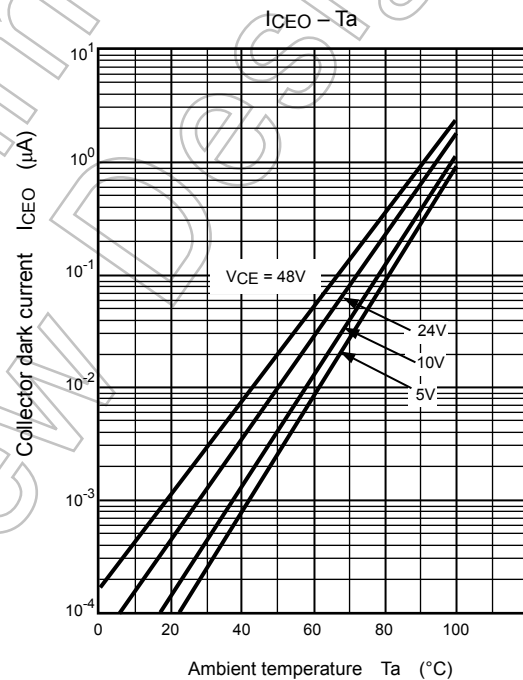
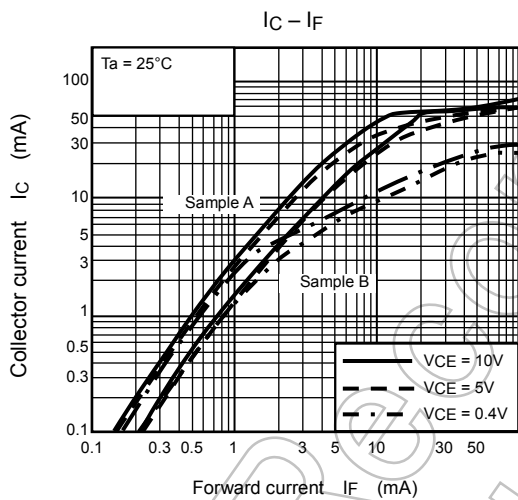
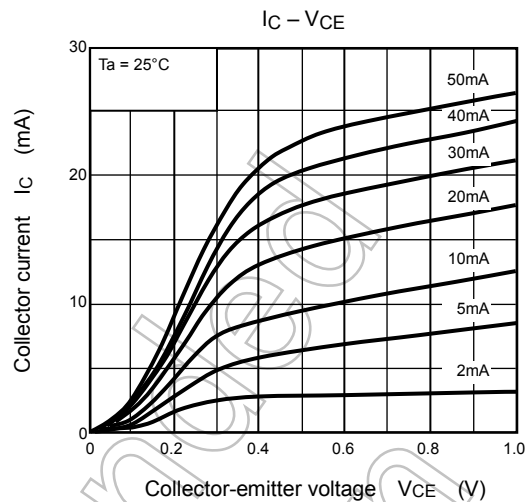
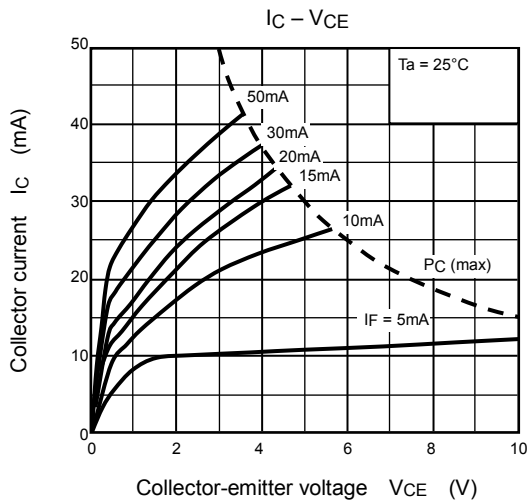
| Characteristic | Symbol    | Test Condition   | Min | Typ. | Max | Unit          |
|----------------|-----------|--|-----|------|-----|---------------|
| Rise time      | $t_r$     | $V_{CC} = 10\text{ V}, I_C = 2\text{ mA}$<br>$R_L = 100\ \Omega$                   | —   | 2    | —   | $\mu\text{s}$ |
| Fall time      | $t_f$     |  | —   | 3    | —   |               |
| Turn-on time   | $t_{on}$  |  | —   | 3    | —   |               |
| Turn-off time  | $t_{off}$ |  | —   | 3    | —   |               |
| Turn-on time   | $t_{ON}$  | $R_L = 1.9\text{ k}\Omega$<br>$V_{CC} = 5\text{ V}, I_F = 16\text{ mA}$<br>(Fig.1) | —   | 2    | —   | $\mu\text{s}$ |
| Storage time   | $t_s$     |  | —   | 25   | —   |               |
| Turn-off time  | $t_{OFF}$ |  | —   | 40   | —   |               |

Fig. 1 Switching time test circuit

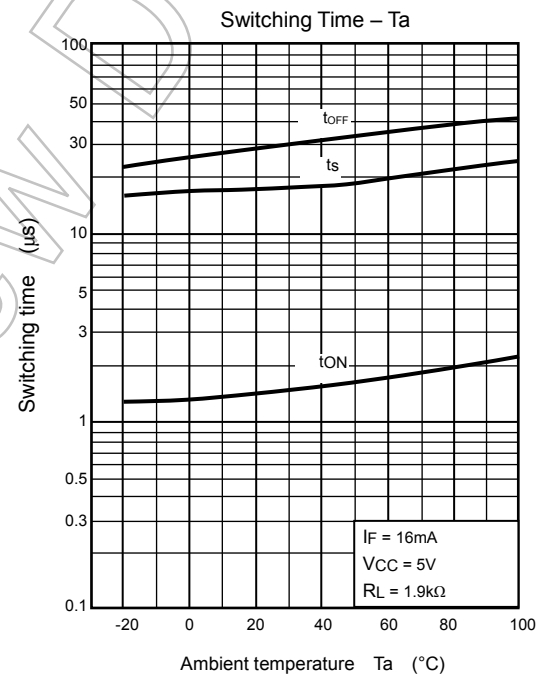
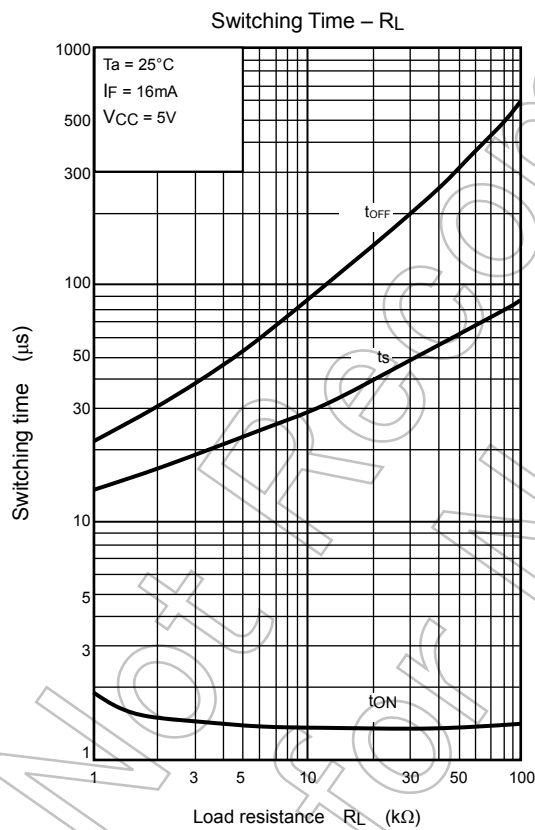
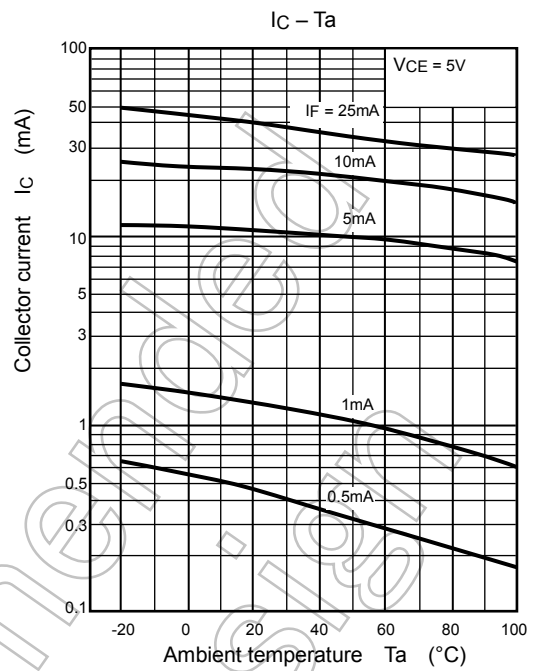
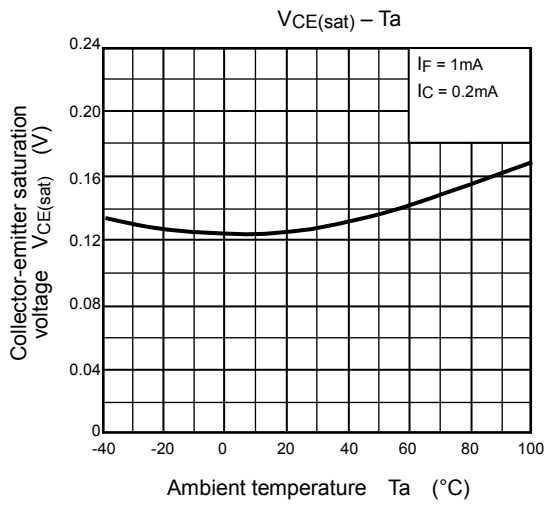




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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